Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.240 inches and 0.290 inches

Terminal Length:

0.150 inches

Overall Height:

0.055 inches

Overall Width:

0.140 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

75.0 breakdown voltage, collector-to-base, emitter open all transistor and 40.0 breakdown voltage, collector-to-emitter, base open all

transistor and 5.0 breakdown voltage, emitter-to-base, collector open all transistor

Current Rating Per Characteristic:

1.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

1400.0 milliwatts small-signal input power, common-collector preset all transistor

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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